

General Description

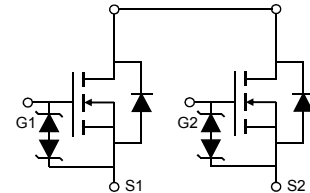
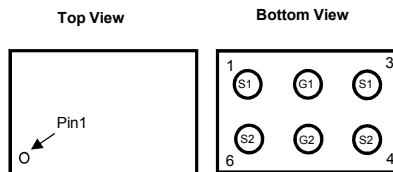
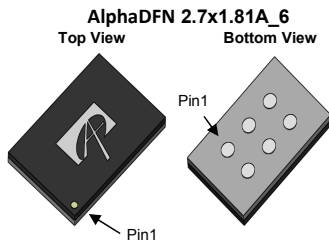
- Trench Power MOSFET technology
- Low $R_{SS(ON)}$
- With ESD protection to improve battery performance and safety
- Common drain configuration for design simplicity
- RoHS and Halogen-Free Compliant

Applications

- Battery protection switch
- Mobile device battery charging and discharging

Product Summary

V_{SS}	12V
$R_{SS(ON)}$ (at $V_{GS}=4.5V$)	< 5m Ω
$R_{SS(ON)}$ (at $V_{GS}=4.0V$)	< 5.3m Ω
$R_{SS(ON)}$ (at $V_{GS}=3.7V$)	< 5.5m Ω
$R_{SS(ON)}$ (at $V_{GS}=3.1V$)	< 6m Ω
$R_{SS(ON)}$ (at $V_{GS}=2.5V$)	< 7m Ω

Typical ESD protection
HBM Class 3A


Orderable Part Number	Package Type	Form	Minimum Order Quantity
AOC3868	AlphaDFN 2.7x1.81A_6	Tape & Reel	5000

Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Rating	Units
Source-Source Voltage	V_{SS}	12	V
Gate-Source Voltage	V_{GS}	± 8	V
Source Current(DC) ^{Note1}	I_S	20	A
Source Current(Pulse) ^{Note2}	I_{SM}	80	A
Power Dissipation ^{Note1}	P_D	2.5	W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Typical	Units
Maximum Junction-to-Ambient $t \leq 10s$	$R_{\theta JA}$	40	$^\circ\text{C/W}$
Maximum Junction-to-Ambient Steady-State		50	$^\circ\text{C/W}$

Note 1. I_S rated value is based on bare silicon. Mounted on 70mmx70mm FR-4 board.

Note 2. PW < 10 μs pulses, duty cycle 1% max.

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
STATIC PARAMETERS						
BV _{SSS}	Source-Source Breakdown Voltage	I _S =250μA, V _{GS} =0V Test Circuit 6	12			V
I _{SSS}	Zero Gate Voltage Source Current	V _{SS} =12V, V _{GS} =0V Test Circuit 1 T _J =55°C			1 5	μA
I _{GSS}	Gate leakage current	V _{SS} =0V, V _{GS} =±8V Test Circuit 2			±10	μA
V _{GS(th)}	Gate Threshold Voltage	V _{SS} =V _{GS} , I _S =250μA Test Circuit 3	0.4	0.72	1.1	V
R _{SS(ON)}	Static Source to Source On-Resistance	V _{GS} =4.5V, I _S =4A Test Circuit 4 T _J =125°C	2.9	4.15	5.0	mΩ
			3.8	5.5	6.6	
		V _{GS} =4.0V, I _S =4A Test Circuit 4	3.0	4.25	5.3	mΩ
		V _{GS} =3.7V, I _S =4A Test Circuit 4	3.1	4.35	5.5	mΩ
		V _{GS} =3.1V, I _S =4A Test Circuit 4	3.2	4.6	6.0	mΩ
		V _{GS} =2.5V, I _S =4A Test Circuit 4	3.5	5.1	7.0	mΩ
g _{FS}	Forward Transconductance	V _{SS} =5V, I _S =4A Test Circuit 3		50		S
V _{FSS}	Forward Source to Source Voltage	I _S =1A, V _{GS} =0V Test Circuit 5		0.59	1	V
DYNAMIC PARAMETERS						
R _g	Gate resistance	f=1MHz		1.2		KΩ
SWITCHING PARAMETERS						
Q _g	Total Gate Charge	V _{GIS1} =4.5V, V _{SS} =6V, I _S =4A		35	50	nC
t _{D(on)}	Turn-On DelayTime	V _{GIS1} =4.5V, V _{SS} =6V, R _L =1.5Ω, R _{GEN} =3Ω Test Circuit8		1.2		μs
t _r	Turn-On Rise Time			3		μs
t _{D(off)}	Turn-Off DelayTime			5.5		μs
t _f	Turn-Off Fall Time			9.5		μs

APPLICATIONS OR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS ARE NOT AUTHORIZED. AOS DOES NOT ASSUME ANY LIABILITY ARISING OUT OF SUCH APPLICATIONS OR USES OF ITS PRODUCTS. AOS RESERVES THE RIGHT TO IMPROVE PRODUCT DESIGN, FUNCTIONS AND RELIABILITY WITHOUT NOTICE.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

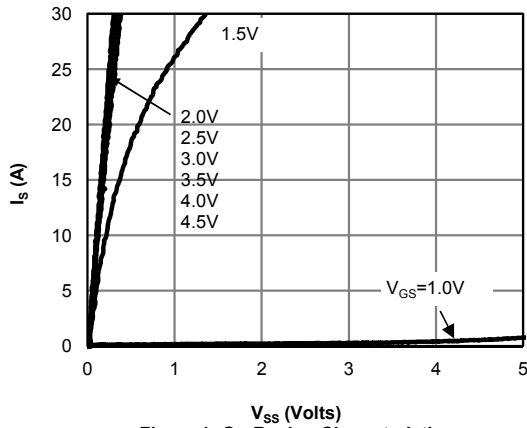


Figure 1: On-Region Characteristics

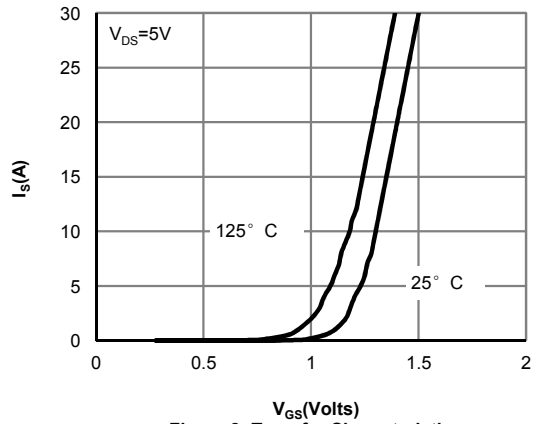


Figure 2: Transfer Characteristics

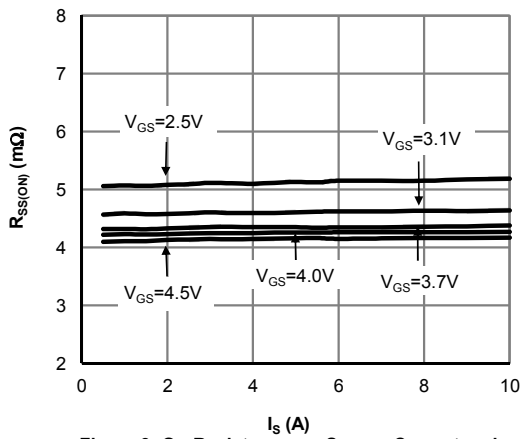


Figure 3: On-Resistance vs. Source Current and Gate Voltage

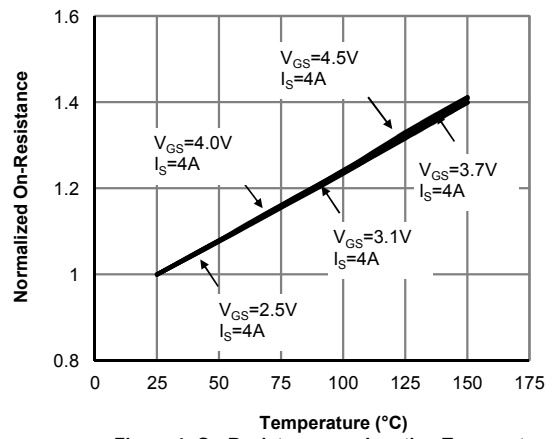


Figure 4: On-Resistance vs. Junction Temperature

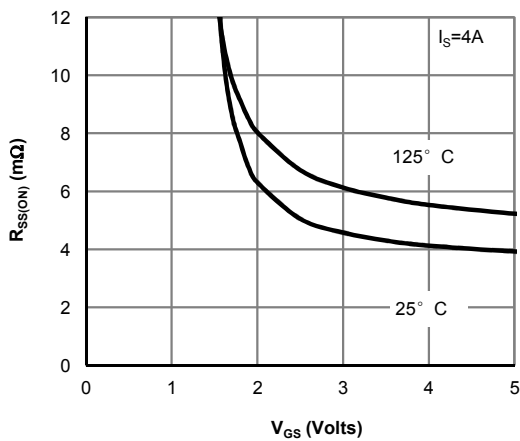


Figure 5: On-Resistance vs. Gate-Source Voltage

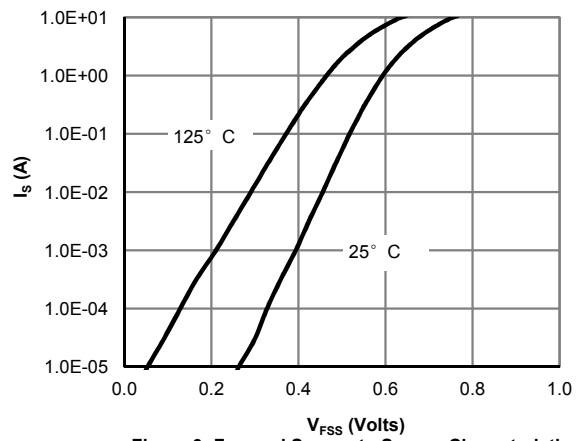


Figure 6: Forward Source to Source Characteristics



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

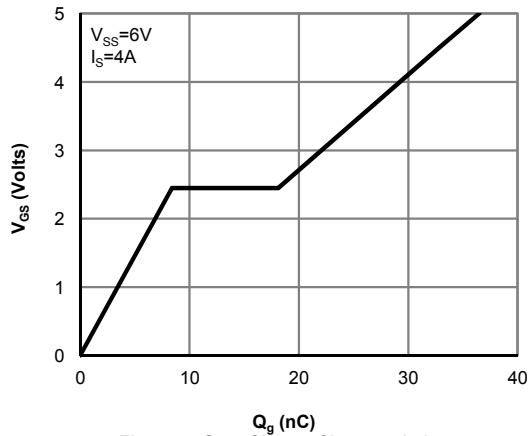


Figure 7: Gate-Charge Characteristics

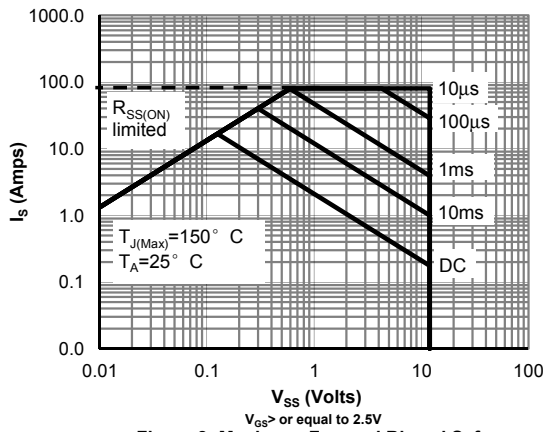


Figure 8: Maximum Forward Biased Safe Operating Area (Note1)

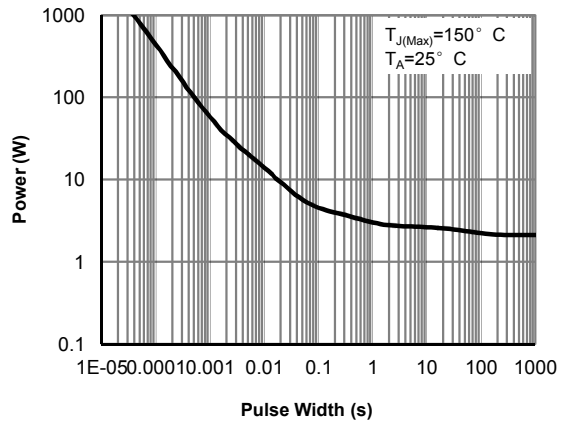


Figure 9: Single Pulse Power Rating Junction-to-Ambient (Note1)

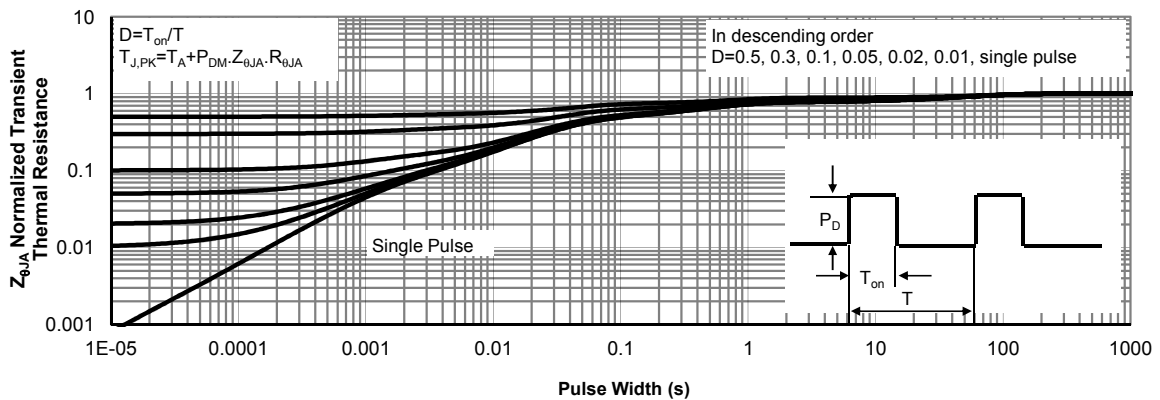
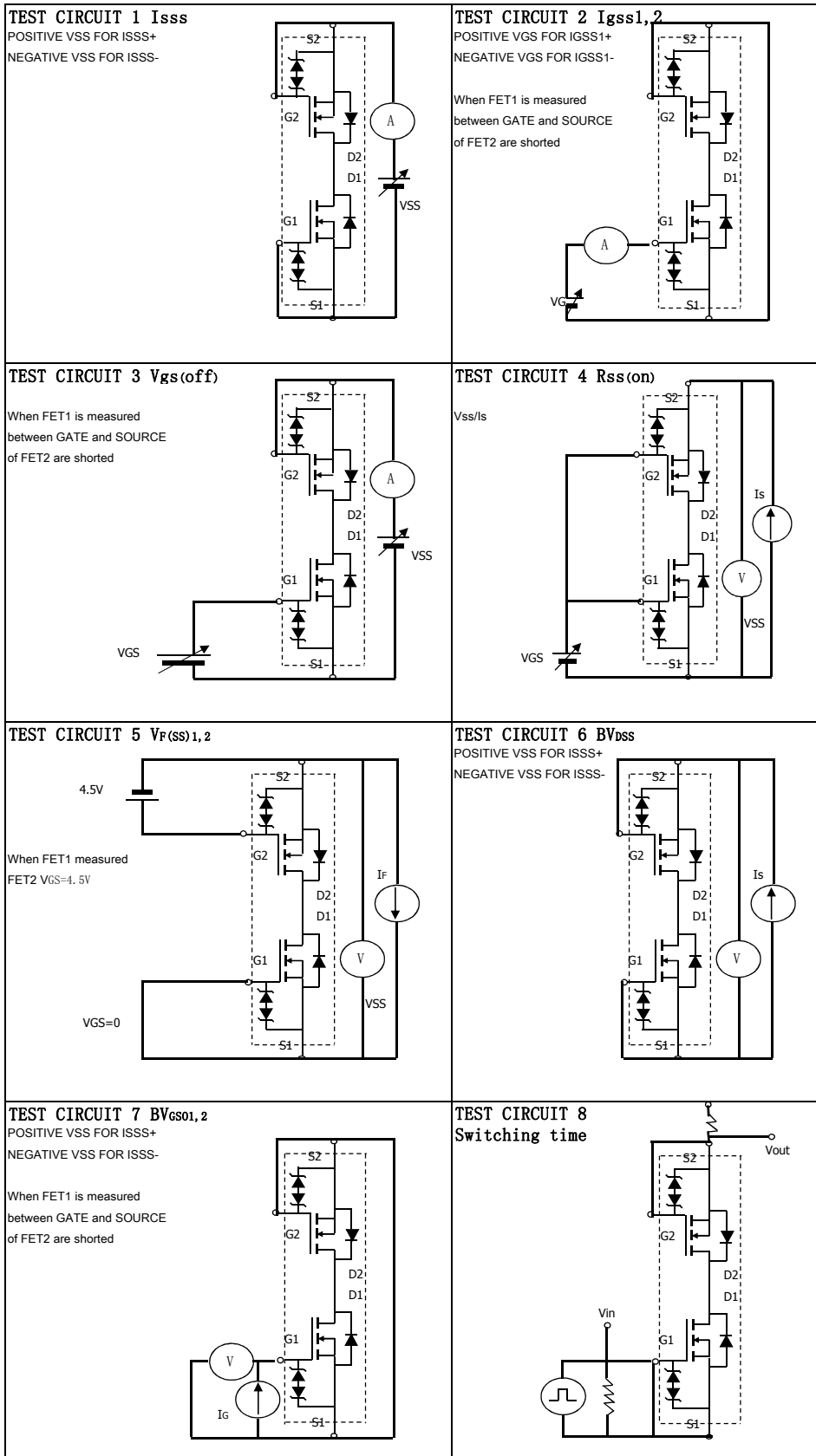


Figure 10: Normalized Maximum Transient Thermal Impedance (Note1)



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [Alpha & Omega](#) manufacturer:

Other Similar products are found below :

[614233C](#) [648584F](#) [FDPF9N50NZ](#) [IRFD120](#) [JANTX2N5237](#) [2N7000](#) [FCA20N60_F109](#) [FDZ595PZ](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#)
[TPCC8103,L1Q\(CM](#) [MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [SSM6J414TU,LF\(T](#) [751625C](#) [IPP110N20N3GXX](#)
[IPS70R2K0CEAKMA1](#) [DMN3404LQ-7](#) [NTE6400](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [ECH8691-TL-W](#)
[FCAB21350L1](#) [P85W28HP2F-7071](#) [DMN1053UCP4-7](#) [NTE221](#) [NTE2384](#) [NTE2903](#) [NTE2941](#) [NTE2945](#) [NTE2946](#) [NTE2960](#) [NTE2969](#)
[NTE2976](#) [NTE455](#) [NTE6400A](#) [NTE2910](#) [NTE2916](#) [NTE2956](#) [NTE2911](#) [TK10A80W,S4X\(S](#) [SSM6P69NU,LF](#) [DMP22D4UFO-7B](#)
[DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)